Delocalization of W annier-Stark ladders by phonons: tunneling and stretched polarons

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We study the coherent dynamics of a Holstein polaron in strong electric elds. A detailed analytical and numerical analysis shows that even for small hopping constant and weak electronphonon interaction, polaron states can become delocalized if a resonance condition develops between the original W annier-Stark states and the phonon modes, yielding both tunneling and 'stretched' polarons. The unusual stretched polarons are characterized by a phonon cloud that trails the electron, instead of accompanying it. In general, our novel approach allows us to show that the polaron spectrum has a complex nearly-fractal structure, due to the coherent coupling between states in the Cayley tree which describes the relevant H ilbert space. The eigenstates of a nite ladder are analyzed in terms of the observable tunneling and optical properties of the system.

The coupling of an electronic system with a coherent boson eld has been a subject of great interest in recent years, thanks to the availability of high quality materials and intense photon sources. In condensed matter systems, how ever, a natural intrinsic eld of bosonic nature is provided by the lattice vibrations. The coupling to phonons is typically considered to result in inelastic incoherent scattering for the electron, as the phonons are di cult to interrogate separately. This results in an electronic bpen' system which exists im mersed in the assumed-incoherent phonon eld. A lthough this description is appropriate for many situations, either because the electron-phonon coupling is weak and/or non-resonant, or if the system is at high temperatures, its validity is suspect if the interaction is electively strong and the temperature is low.

E lectronic transport in superlattices has yielded a num ber of interesting phenom ena and concepts, including B loch oscillations and W annier-Stark (W S) ladders [1], as well as negative di erential conductance [2] in high D C electric elds, dynam ical localization [3], fractional W S ladders under D C and A C electric elds [4], and resonant m agnetopolarons [5]. Sim ilarly, electron-phonon interactions under high electric elds have been investigated in som e detail, including coupled B loch-phonon and -plasm on oscillations [6], as well as phonon-assisted {hopping of an electron on a W S ladder [7]. A pow erful variational treatm ent of inelastic but coherent quantum transport was presented in [8], while anom alies in transport properties under a resonant condition were studied in [9], and the optical absorption associated with the resonance of a W S ladder and con ned optical phonons was studied in Refs. [10,11].

In this paper, we study the e ects of coherent coupling of an electron to the phonon system present in its solid at low tem peratures. We are specially interested in the e ect of this coupling on the tunneling properties of an electron in an intense electric eld region, like the situation achieved in sem iconductor superlattices, for example [12]. Our description is non-perturbative for the resonant case with exponentially large H ilbert space, and as such we are able to elucidate the role of resonant phonon elds on the otherwise localized electron residing in a W S ladder, for both weak and strong coupling. U sing a H olstein m odel for the electron-phonon coupling, and both analytical and num erical techniques, we demonstrate that the electron tends to become more extended for increasing coupling with phonons. Moreover, we show that resonant coupling results in total delocalization of the polaron for some of the states, and the consequent restoring of a h iniband' structure in the system, even as the applied electric eld remains strong. O ther Stretched polaron' states, how ever, are highly degenerate yet strongly localized on one end of a nite structure, with a phonon 'bloud' which is nearly detached from the electron (som ewhat a precursor of the polaron dissociation described in [13]). We are able to show explicitly that the level spectrum in this regime has a nearly fractal structure with rather com plex wave functions. On the other hand, when the system is away from the resonant condition, a deform ed W S ladder results, with electronic wave functions which nevertheless rem ain localized. We nally analyze the tunneling and optical properties one could observe experimentally in such a system.

W e consider a Holstein model [14], describing a single electron in a one-dimensional tight-binding lattice which interacts locally with dispersionless optical phonons. In addition, we consider that a strong constant electric eld is applied which generates a W S ladder. The Ham iltonian is then

where t is the electron hopping constant, ! the phonon frequency, the electron-phonon coupling constant, " $_{j} = edE j$ j the site (or Well') energy, E the electric eld, d the lattice constant, and the spacing between W S Yungs' (we have set h = 1). It is known that well-localized W S states will form in the absence of electron-phonon

interactions, with eigenvalues and eigenfunctions given by "j, and j $_{j}i = P_{i}J_{i}J_{i}(2t=edE)$ jii, where J_{1} is the l-th order B essel function [3]. Given the properties of J_{1} , the W S j-state is clearly localized with a characteristic length 2t=eE around site j. It is helpful to introduce the W S creation and annihilation operators, $d_{j} = \int_{i=1}^{1} J_{i}(2t=edE)c_{i}$: It is easy to show that fd_{i}^{\dagger} ; $d_{j}g = i_{j}$, and that the H am iltonian can be rew ritten in terms of d_{j} ; d_{j}^{\dagger} . In the case of strong electric eld (or small hopping constant) (2t=1), the H am iltonian can be simplified to

$$H = {P \atop j} jd_{j}^{+}d_{j} + !a_{j}^{+}a_{j} + d_{j}^{+}d_{j}(a_{j}^{+} + a_{j}) (a_{j} + a_{j}^{+} a_{j+1}^{+} a_{j+1})(d_{j}^{+}d_{j+1} + d_{j+1}^{+}d_{j}) ;$$
(2)

where the electrive hopping becomes = t=. Notice that phonon-assisted hopping develops between the W S states via the last term . Eq. (2) is similar to that in [10], but here, as the electron jumps it can not only emit (or absorb) a phonon on its current location, but also on the neighboring site. This more natural description results in a much larger relevant H ilbert space for this problem.

Consider the process of an electron jumping between W S states and creating or annihilating a phonon with amplitude , as per the last term in (2). The relevant H ilbert space can be described for n = 3 via the basis: j1;000i; j2;010i; j2;100i; j3;011i; j3;010i; j3;020i, and j3;110i. Each state jj;m₁;m₂;:::i is indexed by the electron position j, and m_k refers to the number of phonons on site k. This construction yields a H ilbert space of dimension N $1 = 2^{i}$ 1, where n is the total number of sites in the chain. It is interesting to note that the structure of this vector space is that of a Cayley tree where each j-state links to two at j + 1, in general with non-symm etric weights in all branches [15]. A sim ilar structure of the vector space was found in [8].

Under the resonance condition, i.e., = !, all the basis-states in the H ilbert space described above have the same energy, and one would expect that the o -diagonal matrix elements in (2) would break the degeneracy. One would expect that a miniband' of extended states might form, whenever the resonance condition is reached. For this case, H am iltonian (2) in the above basis of n = 3 takes the form

with ever larger blocks for larger n values. Notice that there are elements with some what unusual values, $\frac{1}{2}$, associated with the higher number of phonons in state β ;020i. A similar structure is seen for all values of n, and as these terms appear only sporadically, they have only a small in uence on the overall level structure. In particular, one expects that there would be little change in the physics in the limit of large N, if we replace $\frac{1}{2}$ terms with the same description is in fact con med explicitly by numerical calculations. Moreover, this symmetrized' H am iltonian H sym allows one to better analyze the structure of the solutions of H, as we show below, while exhibiting some of the same generic features and fully self-sim ilar properties.

Sym m etrized H am illonian. By using the block decomposition of the determ inant, det $\begin{bmatrix} A & B \\ C & D \end{bmatrix} = \det(D) \det(A = D)$; one can nd that the eigenvalues of H_{sym} are determined by the equation $\mathbf{m}_{0}^{N=2}\mathbf{m}_{1}^{N=4}\mathbf{m}_{2}^{N=8}$ $\mathbf{n}_{1}\mathbf{n}_{2}^{N=0}$; where $\mathbf{m}_{0} = \mathbf{m}$, \mathbf{m} is the energy eigenvalue, and $\mathbf{m}_{k+1} = \mathbf{m}_{2}^{2} \mathbf{m}_{k}^{N}$: Here we have made a constant energy shift of . One can then write \mathbf{m}_{k} as a continuous fraction in k steps

$$\mathbf{u}_{k} = \mathbf{u} - \frac{2^{2}}{\mathbf{u} - \frac{2^{2}}{\mathbf{u} - \frac{2}{\mathbf{u}}}}$$
: (4)

and the eigenvalues of H sym are given by [11] [16]

$$\mathbf{w}_{k,1} = 2^{p} \overline{2} \cos \frac{1}{k+1}$$
; (5)

where k = 1;2; ...; n; l = 1; ...; k. The lim iting bandwidth of the spectrum is $4^{p}\overline{2}$.

U sing H sym , one can arrive at an estimate for the degeneracies for the rst few eigenvalues in the limit of large N , given by the equation $"^{3N=8}$ ($"^2$ 2^2)^{N=8} ($"^2$ 4^2)^{N=8} = 0. One then has eigenvalues " = 0 with degeneracy 3N=8,

" = $\frac{P}{2}$ with degeneracy N =8, and " = 2 with degeneracy N =8, in agreement with our explicit calculations for nite N. Notice that increasing lattice or chain size produces both new energy eigenvalues within the limiting band and additional states which augment the degeneracy of som e of the old eigenvalues. The overall structure of the spectrum remains the same and all the eigenvalues of the shorter chain are also in the spectrum of the longer one [17].

Figure 1 shows typical numerical results for the eigenvalues of the physical H am iltonian H in Eq. (2), while the inset shows the results for the symmetrized version H_{sym} (both for n = 8). Our analytical results match exactly those shown in the inset, which in turn m in ic well the results for H in the main panel, although sm all di erences appear due to the sporadic 2 terms. The self-sim ilar structure of the spectrum in the inset is the manifestation of the full self-sim ilarity of the H am iltonian H_{sym} (while it is only approximate for H). One can see that the original highly degenerate H ilbert basis is split into a sem i-continuous h iniband' by the o -diagonal elements in H (and which for H_{sym} yields Eq. 5 for large N). Notice, how ever, that there are large residual degeneracies for the eigenvalues of H in the center of the m iniband. The right panel in Fig. 1 shows the density of states of the H system, exhibiting also an approximate self-sim ilarity.

The Electronic wave functions' for various sample eigenstates are shown in Fig. 2, P_{*}(j) = $\Pr_{\text{fm g}} \mathcal{L}_{j;\text{fm g}}^{"} \mathcal{J}$, where the "-eigenstate is given in term s of the basis above by j *i = $\Pr_{j;\text{fm g}} \mathcal{L}_{j;\text{fm g}}^{"} \mathcal{J}$; fm gi. 0 ne can observe that the states in regions of high degeneracy, " = 0 and " = 1:6 (where states (A) and (C) are indicated), are localized around the right end of the structure, j 8. How ever, non-degenerate states in the band, such as the one labeled (B), result to be fully extended over the structure.

Notice that in this inherently coupled electron-phonon system, the calculated eigenstates are a coherent mixture of electron and phonons on di erent sites. The am plitudes in Fig. 2 have been projected over all phonon com ponents. Sim ilarly, in order to illustrate the physics of these states better, one can exhibit the average phonon number for various states in Fig. 3. One can see clearly that all states at the degenerate center of the band have m any m ore phonons (' 7) than those non-degenerate states residing higher in the band. It appears, in fact, that when the electron interacts with m any phonons, it localizes, as one would perhaps intuitively expect for polaron self-trapping states, while states with fewer phonons are less localized and propagate' better. One can provide an estim ate for the average num ber of phonons for extended states by the following argument: The average phonon num ber is given by $_{i}$ P $_{i}$ N $_{i}$, where P $_{i}$ is the probability for an electron to be at site i, and N $_{i}$ is the number of phonons in this hNi= state. For an extended state, Pi' 1=n, where n is the number of sites. A state with an electron at site i can be obtained by the electron hopping i 1 steps from the rst site, while emitting $N_i = D_i$ 1 phonons in the process. W e then obtain that the average number of phonons for an extended states is hN i ' _i(i 1)=n = (n 1)=2. This result m atches well the num erical results, where the m ost extended states have hN i' 3:5 in Fig. 3, such as the state labeled (B).

O ne can also inspect the spatial distribution of phonons for each state, as in the inset of F ig. 2, which shows the corresponding phonon distribution for several eigenstates, $N_{*}(j) = \int_{l_{fm}} jg \int_{l_{fm}} jg jm_{j}$, indicating how the phonons distribute over the chain. The degenerate states, such as (A) and (C), with the electron localized to the right of the structure, have nearly one phonon per site throughout the chain, indicating that these polarons have a 'stretched' phonon cloud away from the charge, seem ingly in anticipation of the total polaron dissociation that other authors have described for extended chains under high electric elds [13]. In contrast, the most delocalized states (such as (B) in Fig. 2) show a phonon am plitude much less than unity throughout, yielding an overall low phonon count, and a cloud that in general 'accom panies' the charge.

Interband optical absorption. The spectrum of optical absorption associated with transitions between valence and conduction bands provides inform ation about the density of states and the states' charge distribution. The absorption intensity K is calculated from $K = \frac{2}{h} \mathbf{j} \mathbf{V} + \mathbf{f} (\mathbf{I} + \mathbf{E}_g + \mathbf{j})$, where \mathbf{E}_g is the valence and conduction band gap, refers to the various polaron states, and W is the transition matrix between valence band and conduction band states. Under the strong eld present in the system, the hole is localized the most because of its large elective mass. Thus we ignore its negligible tunneling and coupling to phonons and assume it localized at site 1. Correspondingly, there is conservation of phonon number and $\mathbf{j} \mathbf{V} + \mathbf{I} (\mathbf{I})$ [18]. In Fig. 4(a) we show the absorption intensity vs. phonon frequency. Once again, we see that the non-degenerate states, $\mathbf{I} = \mathbf{I} - \mathbf{I} + \mathbf{I} + \mathbf{I} + \mathbf{I} = \mathbf{I}$ and will then contribute the most to the absorption spectrum. In contrast, all highly degenerate states at $\mathbf{I} = 0$ are strongly localized at the right end of the chain and make a vanishing contribution to K. Such strong m odulation of K would be easily accessible to experiments.

Transport properties. As described above, tunneling experiments under strong electric elds are possible in semiconductor superlattices and other systems, and it is of interest to investigate the role of the resonance condition. The transition probability P can be calculated in a S-m atrix form alism. P = $\int f f$ and T = $h_{f}^{"}$; R $f f_{i}^{"}$; L i. Here R and L refer to the right and left leads. In the wide band lim it, T / $dt_{1}dt_{2}e^{i("_{f}t_{2}} = "_{it_{1}}) \ln f^{R}$ ($t_{2} = t_{1}$) ji = lim j in jii ("_{f} = "_{i}), where describes the electron interaction with contacts, and G^R is the retarded G reen function connecting both ends of the structure (the site j = 1 and j = n) [19]. We use D () = jnj in $jlij_j = P$ (1)P (n) to describe the relative contribution of various eigenstates to the electronic transport, as the tunneling probability is proportional to the density of states in the leads and D () [19]. Figure 4(b) shows the quantity D ("). We can see that all the states at the center of the band contribute zero to the transport am plitude through the chain, and that this behavior is exhibited by all the high peaks in the DOS, clearly consistent with their spatially localized-charge nature. On the other hand, D shows large values for extended states, con mming in fact that the non-degenerate states in the miniband are extended. The variations shown in D would then be rejected in strong am plitude m odulations within each of the phonon replicas in tunneling experiments [20], whenever the resonance condition is reached. It is also clear that despite the fact that K and D correspond to completely di erent physical quantities, their energy behavior is suprisingly sim ilar. This arises because of the large electric eld asymmetry, resulting in no states with mostly/only large electronic am plitude in the rst site (i.e., localized tow ands the left of the chain). Once a state is extended and has non-vanishing am plitudes at site 1, it also does at site n.

So far we have mainly described the resonant case. When the system is away from the resonant condition, a deform ed lattice with substructure is form ed. We are also able to study the system beyond small hopping and weak coupling regime by mapping it via the Lang-Firsov canonical transformation to the case we have studied, with renormalized hopping and coupling constants. In this approach, we can provide additional physical insights into some interesting results found in [8]. We will report the details elsew here [17].

A lthough ourm odel is 1D [12], we expect the qualitative features and m ain conclusions to be valid for sem iconductor superlattices (SLs) where electron (optical-phonon coupling is highly anisotropic. In that case, it would be possible to neglect the in-plane scattering of electrons by phonons, while the strong interaction assists in the electron hopping. In fact, for SLs with low in-plane disorder, the transitions between di erent layers involve states near the bottom of the 2D electron subbands and phonons with sm all in-plane momenta. Hence, the system would exhibit quasi-1D behavior, and in-plane scatterings are a sm all correction. Sim ilarly, we could adapt our model to the description of polarons in polymer chains, such as those described in R ef. [13], although there the electron-phonon interaction is of di erent strength than in solid SLs, and tunneling experiments are rather more challenging.

We have studied the coherent dynam ics of Holstein polarons in a strong electric eld. It is found that with the help of phonons, each WS rung develops into a 'miniband' under the resonance condition. This miniband shows a nearly self-sim ilar structure, which is inherited from the full self-sim ilarity of the Ham iltonian H_{sym} for a sym metric Cayley tree. A lthough the phonons can help the electron jump from one WS state to another, the phonons can also prevent the electron from propagating. If too many phonons are involved, this results in highly degenerate states with the electron localized at one end of the structure while the phonons are pulled away from it (the Stretched' polaron). The miniband structure and its modulations in density of states and other characteristics are manifested in both transport and optical properties of the system, which we anticipate can be observed in experiments at low temperatures [12].

ACKNOW LEDGMENTS

This work was supported in part by US DOE NO.DE {FG 02{91ER 45334.

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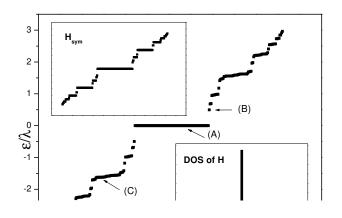


FIG.1. Energy spectrum for H structure of spectrum for H $_{\rm sym}$, a A to C relate to Fig.2. Here, =

n = 8. Notice clear fractal
m etric about " = 0. Labels

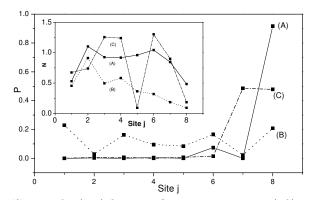


FIG.2. Electronic am plitudes P (j) at each site j for several states, A to C, as indicated in Fig.1. Notice A and C are localized near j' 8. Panel shows phonon content N (j) for same states. A and C have large phonon counts throughout and away from the electron, resulting in Stretched' polarons.

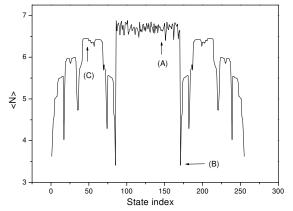
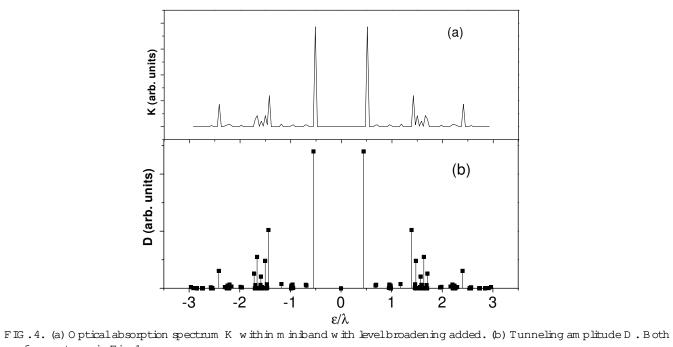


FIG.3. Total phonon num ber for each eigenstate. Highest values plateau for the most localized electronic amplitudes, A and C, while lowest counts correspond to extended electronic states, such as B.



cases for spectrum in Fig. 1.